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# SILICON SOLAR CELLS – CURRENT PRODUCTION AND FUTURE CONCEPTS

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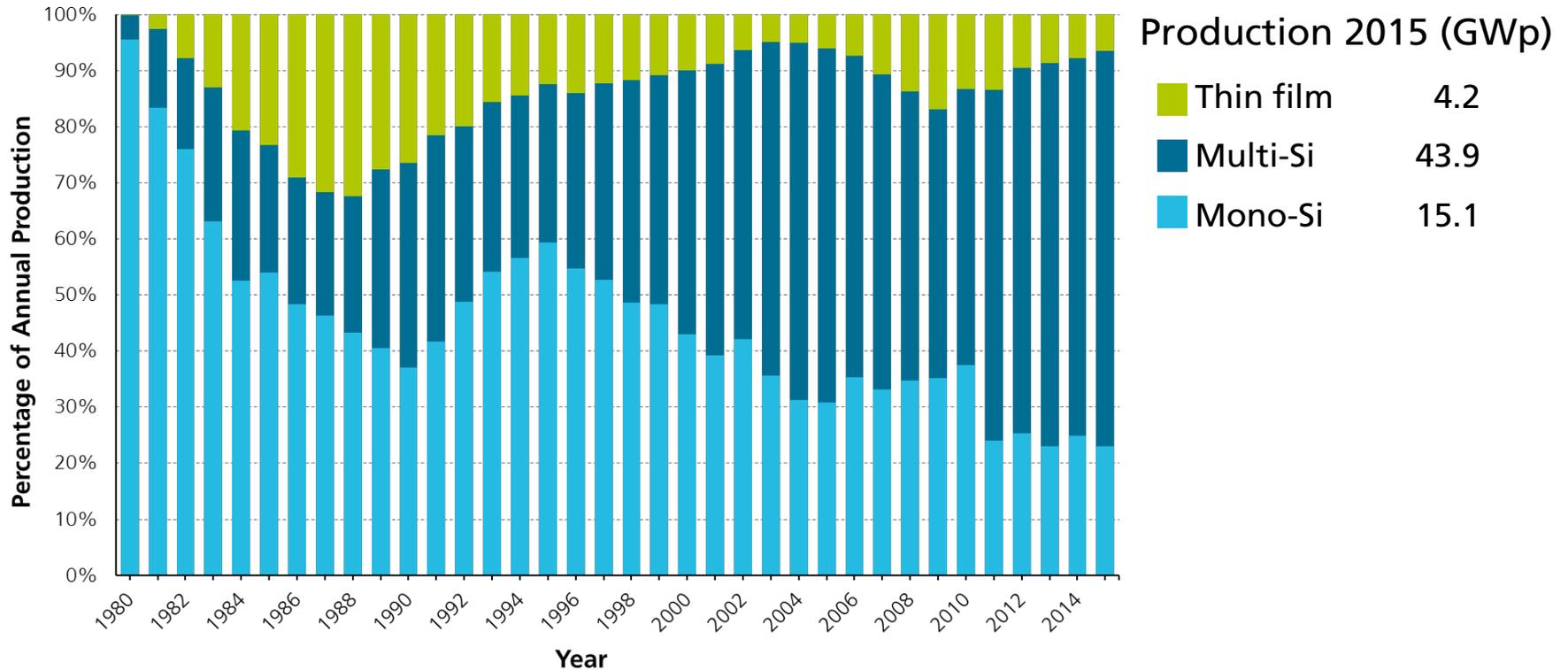
19. 05. 2017

PV Manufacturing in Europe

Brussels

# PV Module Production Development by Technology

## It is still silicon ...



Data: from 2000 to 2010: Navigant; from 2011: IHS (Mono-/Multi- proportion from cell production). Graph: PSE AG 2016

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# SILICON SOLAR CELLS – CURRENT PRODUCTION AND FUTURE CONCEPTS

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## ■ PRESENT

- Current production of silicon solar cells
- Evolution of cell efficiency → The pathway to highest efficiencies

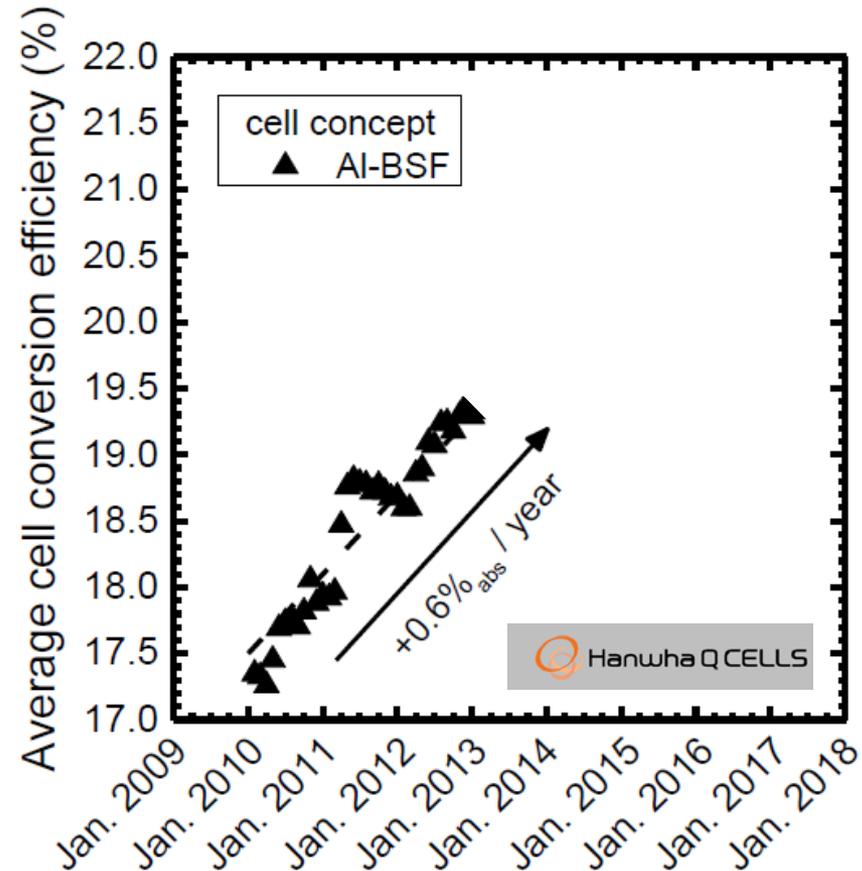
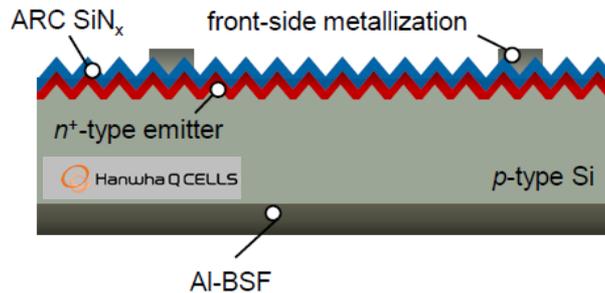
## ■ FUTURE

- Overcoming the limits of silicon
- A new generation of silicon solar cells

# Present

## Screen-printed Al-BSF Solar Cell on p-Type Silicon

- Production data from Hanwha Q CELLS

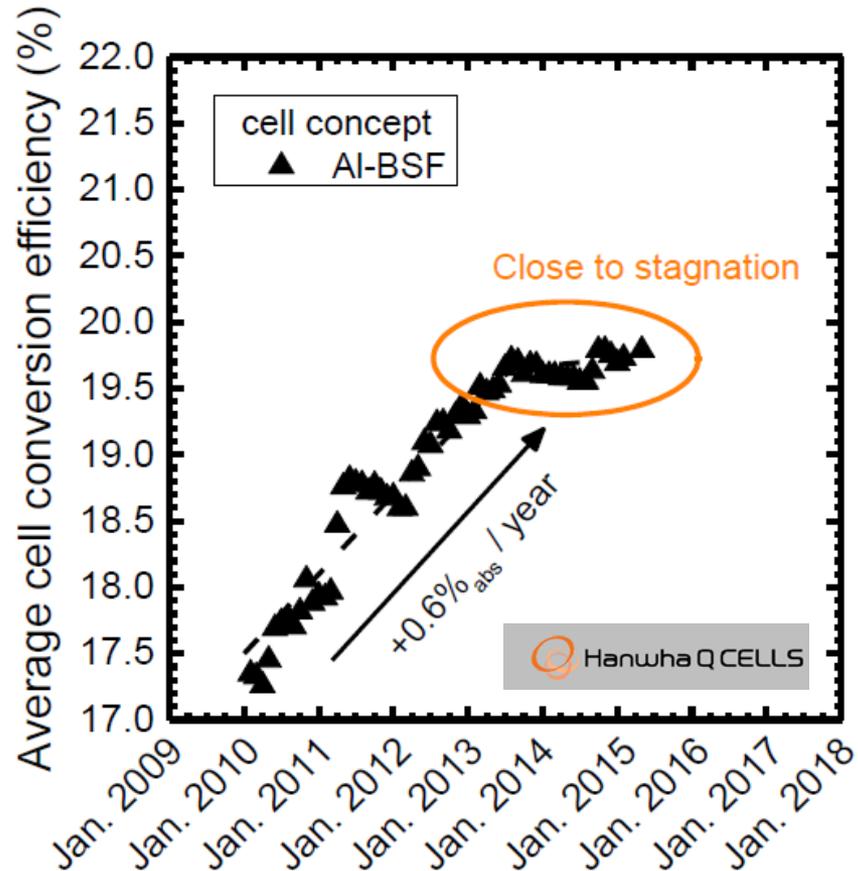
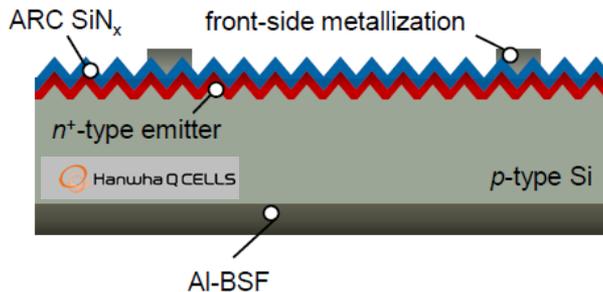


Fabian Fertig et al "Mass Production of p-Type Cz Silicon Solar Cells ..."  
7<sup>th</sup> Silicon PV, Freiburg, Germany, April 3, 2017

# Present

## Screen-printed Al-BSF Solar Cell on p-Type Silicon

- Production data from Hanwha QCELLS
- Efficiency limitation due to full area Al-BSF rear side
- What is the next step?
  - Make it cheaper?
  - Make it better?

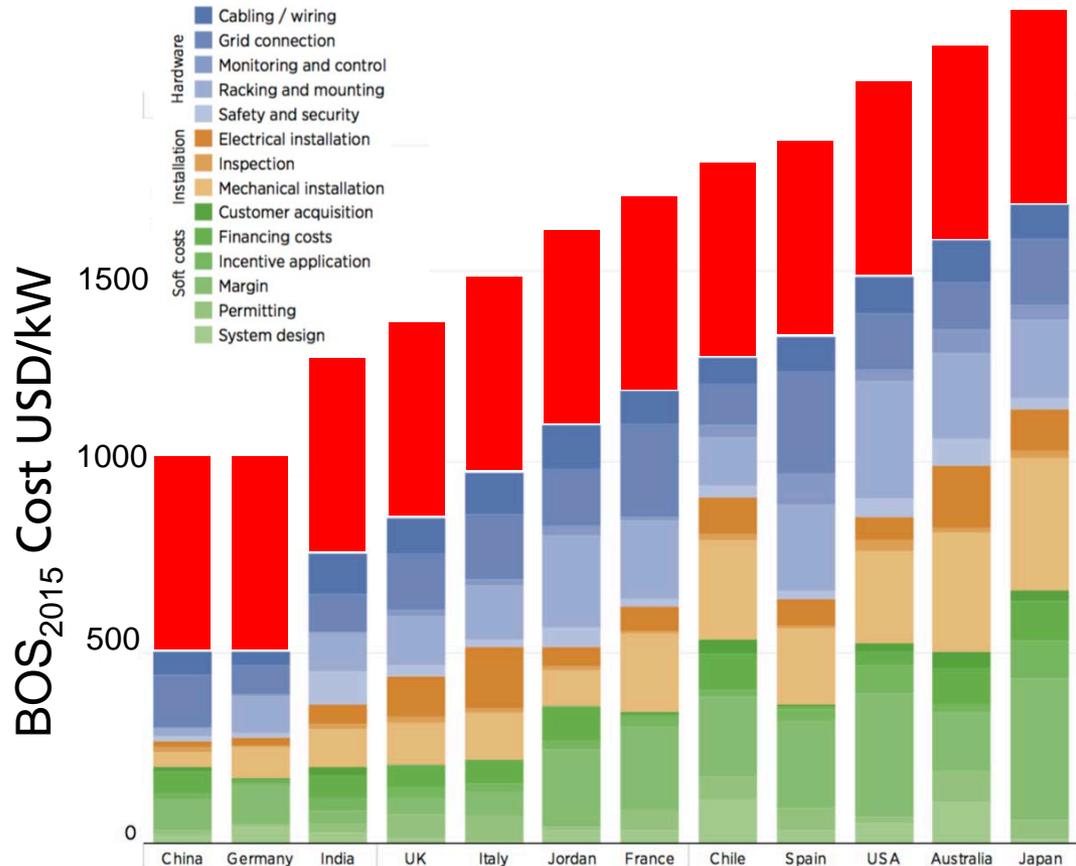


Fabian Fertig et al "Mass Production of p-Type Cz Silicon Solar Cells ..."  
7<sup>th</sup> Silicon PV, Freiburg, Germany, April 3, 2017

# Present

## System Cost: BOS and Module Costs

- Different BOS for different Countries
- Current **Module** price < 0.5 \$/W
- Module price only a small fraction of system cost in most countries



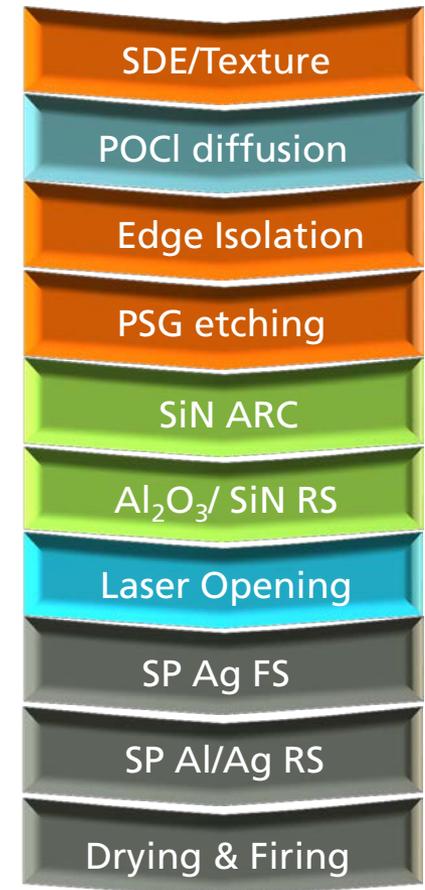
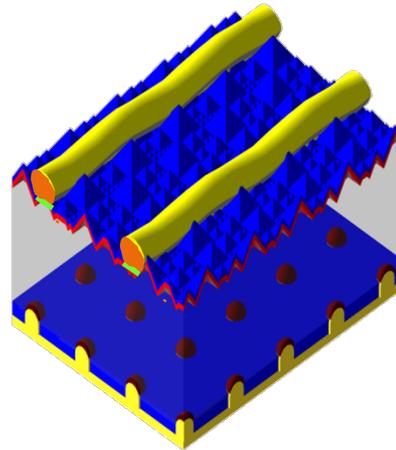
→ **Highly efficient solar cells reduces System Cost and the LCOE**

IRENA (2016), The Power to Change: Solar and Wind Cost Reduction Potential to 2025

# Present

## From Al-BSF to PERC

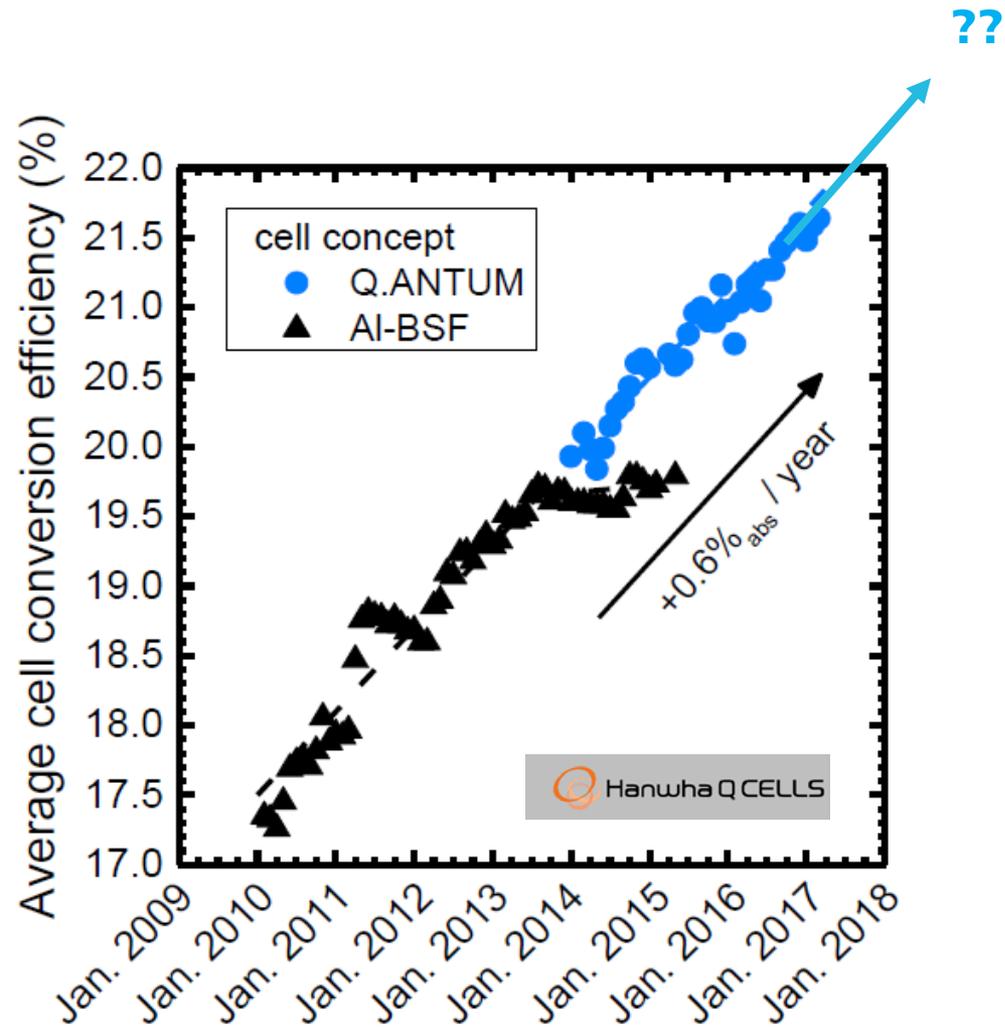
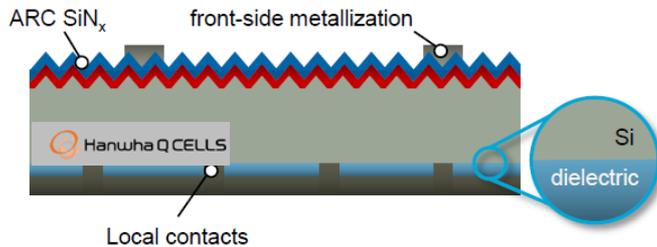
- Replacement of the full area Al-BSF with a **partial rear contact (PRC)**
- Two additional process steps
  - Dielectric passivation
  - Local contact opening (LCO) or Laser fired contact (LFC)



# Present

## From AI-BSF to PERC

- Q.ANTUM production data from Hanwha QCELLS
- Still 0.6 %<sub>abs</sub>/year efficiency improvement
- How far can we go?

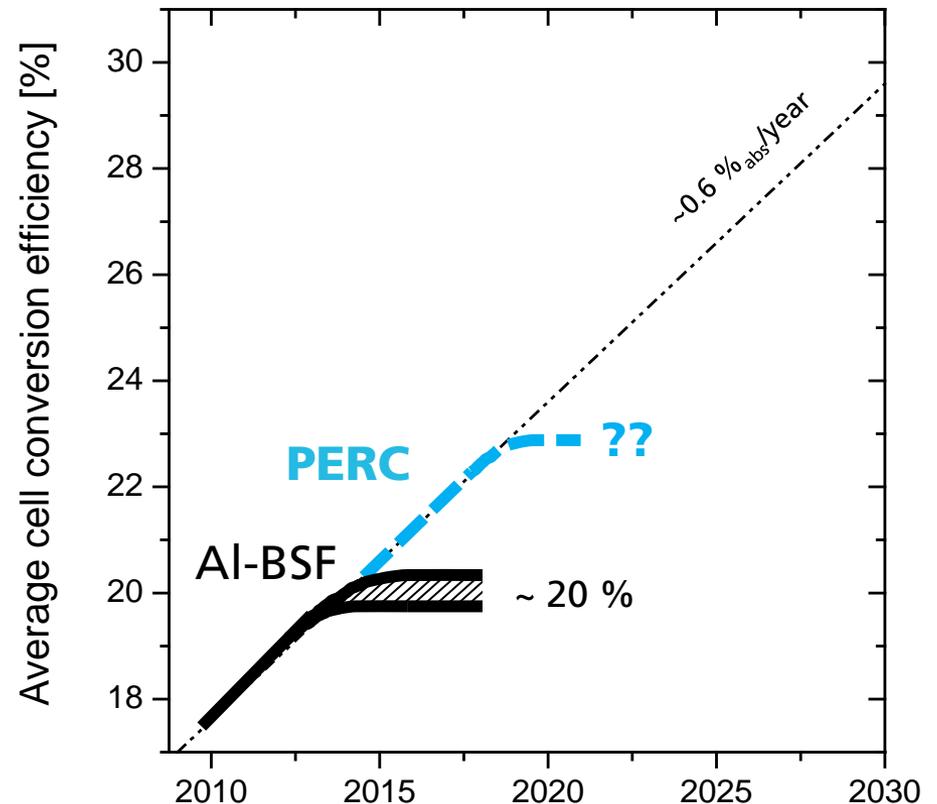


Fabian Fertig et al "Mass Production of p-Type Cz Silicon Solar Cells ..."  
7<sup>th</sup> Silicon PV, Freiburg, Germany, April 3, 2017

# From Present to Future

## Silicon Solar Cell Production: What is the Efficiency Limit?

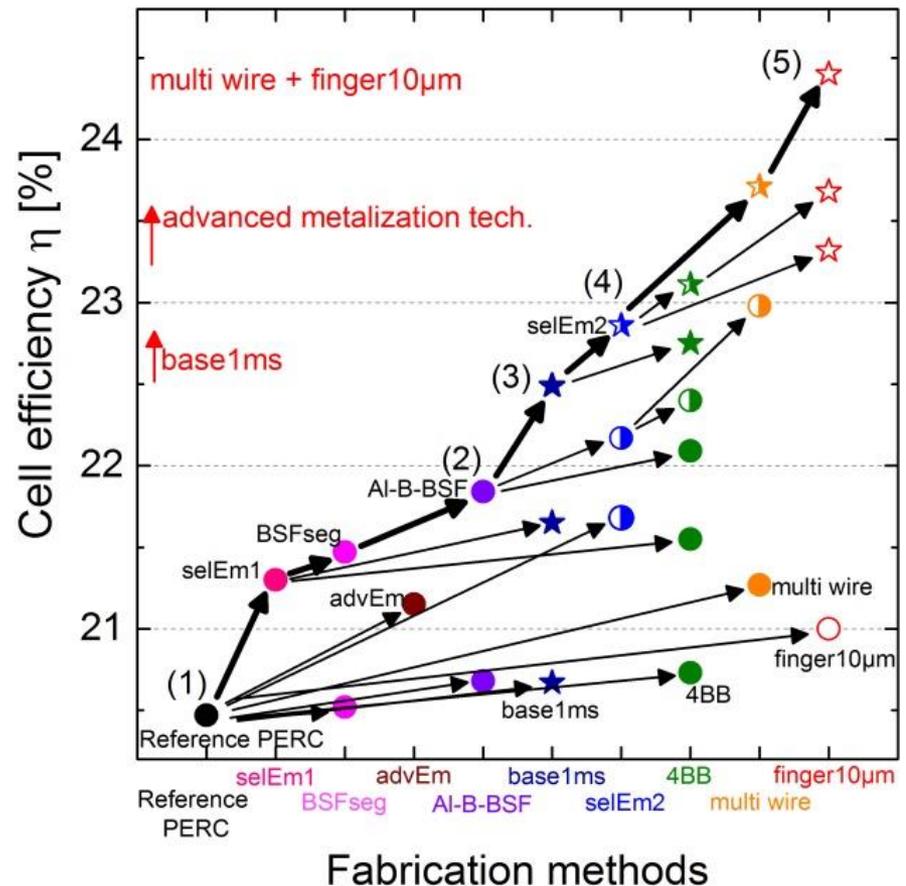
- Assuming constant *"learning curve"*  
→ efficiency improvement  
~0.6 %<sub>abs</sub>/year
- What limits the cell efficiency and which technologies are needed in the future ?



# From Present to Future

## PERC – What is the Limit

- Continuous increasing is possible by
  - Improving base lifetime > 1 ms
  - Smaller fingers and smaller selective emitter regions
  - Multi-wire Module



B.Min et al , *INCREMENTAL EFFICIENCY IMPROVEMENTS...*, 31st EUPVSC 2015, Hamburg

# From Present to Future

## PERC – What is the Limit

### ■ Continuous increasing is possible by

■ Improving base lifetime > 1 ms



No material degradation, cleaner processes/environment

■ Smaller fingers and smaller selective emitter regions



Higher alignment accuracy, increased metallization costs (e.g. screens)

■ Multi-wire Module

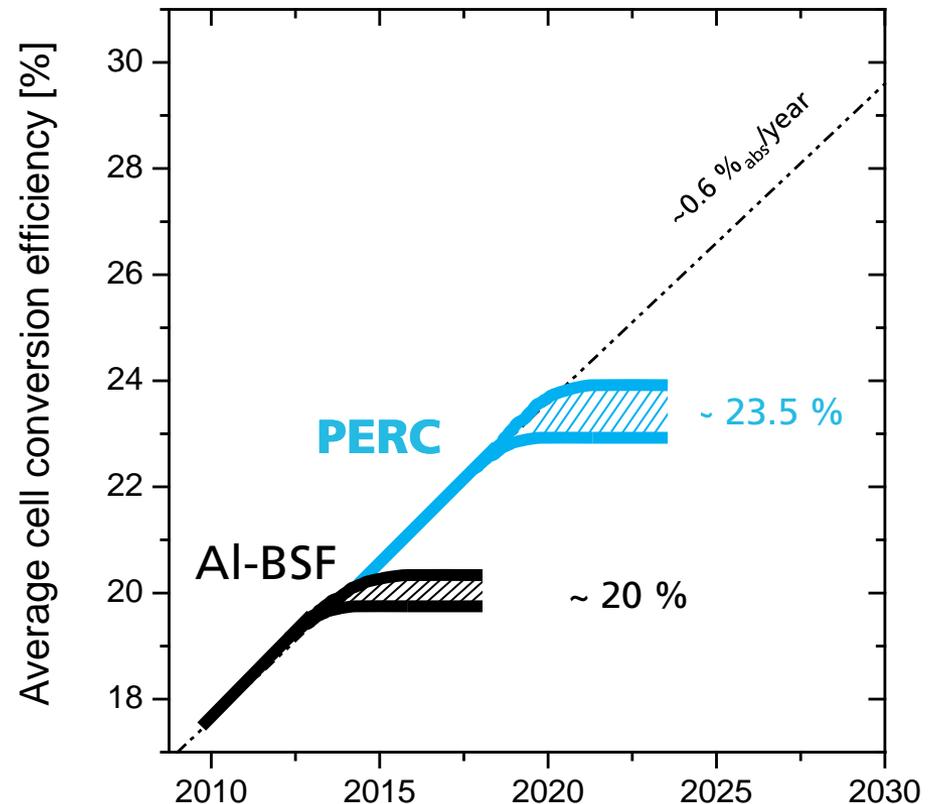


Higher CTM losses, higher module manufacturing costs

# From Present to Future PERC – What is the Limit

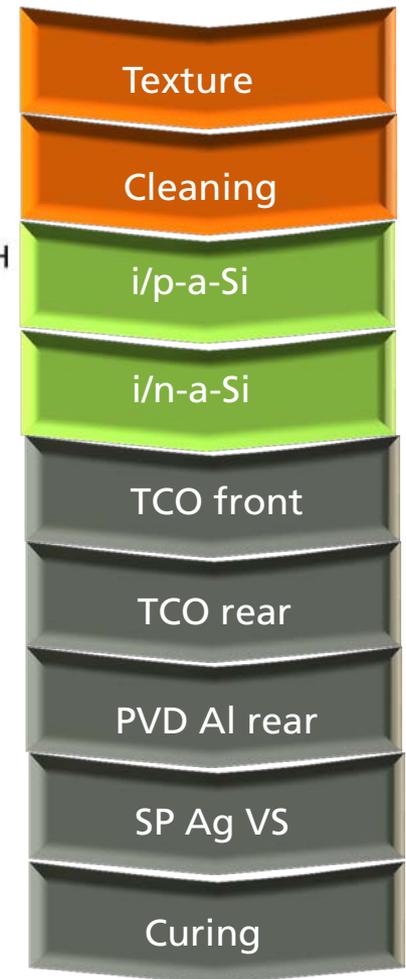
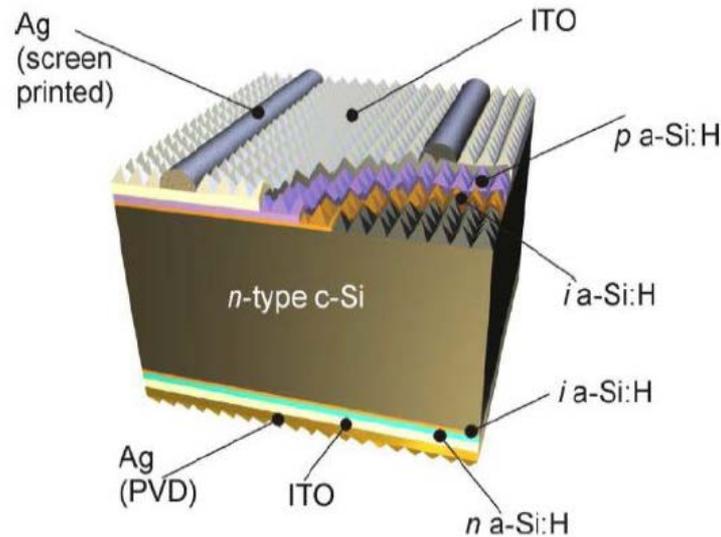
- Physical Limitations
  - Contact recombination and lateral current flow

→ **Passivating Contacts**



# From Present to Future Heterojunction Solar Cells

- Lean process flow
- Highly efficient carrier selective contacts
- High  $V_{oc}$  and low  $T_k$
- Parasitic absorption
- Metallization temperature is limited

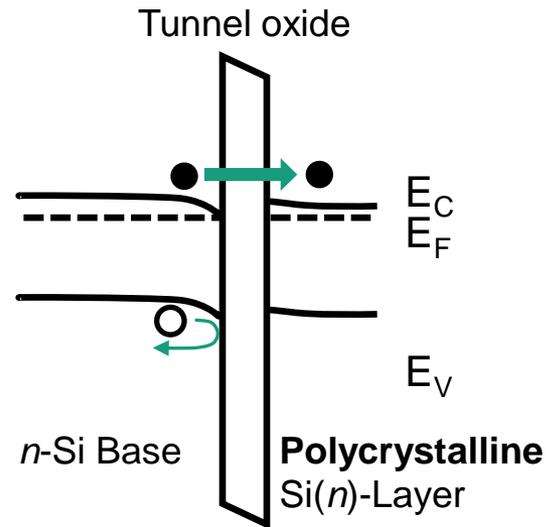
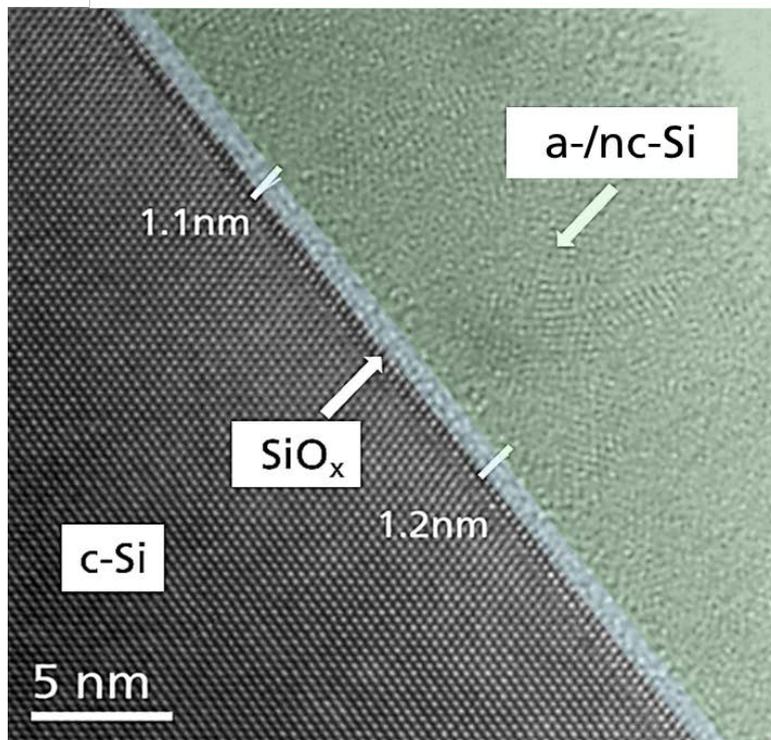


from: D.Bätzner Silicon PV 2014

# From Present to Future

## Passivating Contacts with Oxide and Polysilicon

**TOPCon Structure**



Post, IEEE Transactions on Electron Devices (1992)

F. Feldmann et al., *SOLMAT* 120 (2014)

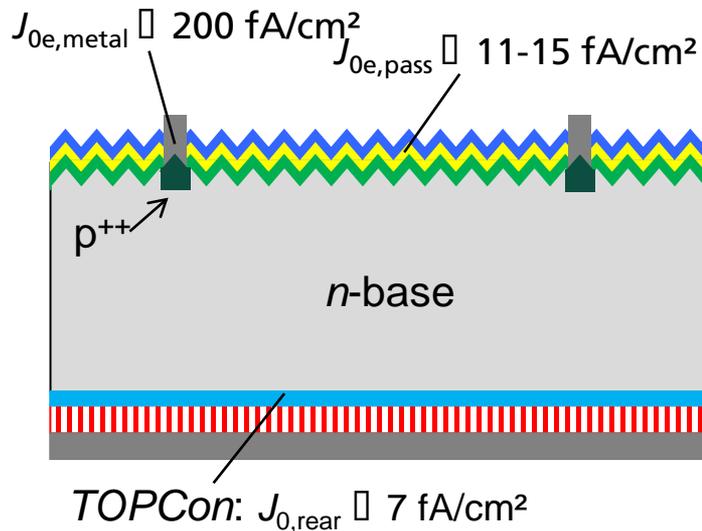
U. Römer, et al. IEEE Journal of Photovoltaics (2015)

D. Yan Solar Energy Materials and Solar Cells (2015)

# From Present to Future

## TOPCon Record Cells with Top/Rear Contacts

Material	Area	$V_{oc}$ [mV]	$J_{sc}$ [mA/cm <sup>2</sup> ]	$FF$ [%]	$\eta$ [%]
<i>n</i> -type Mono	4 cm <sup>2</sup> (da)	725	42.5	83.3	<b>25.7*</b>



→ World record efficiency of **25.7%** for both side contacted solar cells

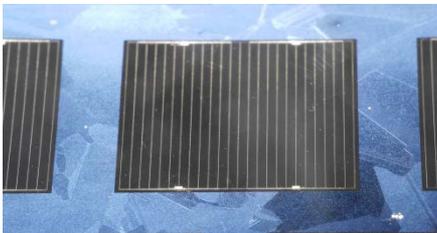
A.Richter *Silicon Solar Cells with Passivating Rear Contacts*  
 7<sup>th</sup> Silicon PV, Freiburg, Germany, April 3, 2017

\* confirmed by Fraunhofer ISE Callab

# From Present to Future

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<i>n</i> -type Multi	4 cm <sup>2</sup> (ap)	673	40.8	79.7	<b>21.9*</b>



Photograph of the *n*-type HP mc solar cell

→ World record efficiency of **21.9%** for a mc silicon solar cell

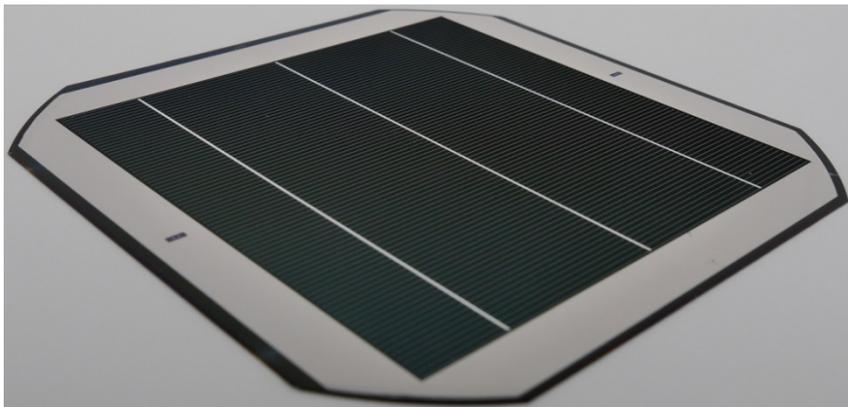
J. Benick *High-efficiency multicrystalline n-type silicon solar cells* 7<sup>th</sup> Silicon PV, Freiburg, Germany, April 3, 2017

\* confirmed by Fraunhofer ISE Callab

# From Present to Future

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<i>n</i> -type Multi	4 cm <sup>2</sup> (ap)	673	40.8	79.7	<b>21.9*</b>
<i>n</i> -type Mono	100 cm <sup>2</sup> (ap)	713	41.4	83.1	<b>24.5*</b>



→ Process scalable on larger area

F.Feldmann, **Evaluation of TOPCon technology on large area solar cells** EUPVSEC, Amsterdam, 2017

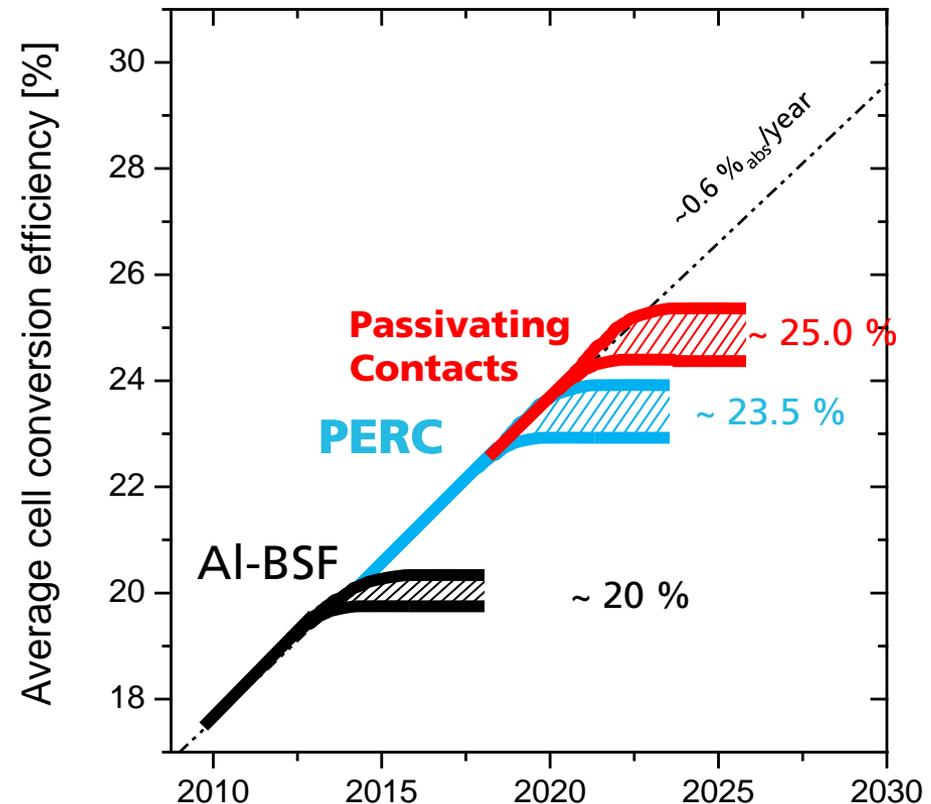
\* confirmed by Fraunhofer ISE Callab

# From Present to Future

## Passivating Contacts – What is the limit

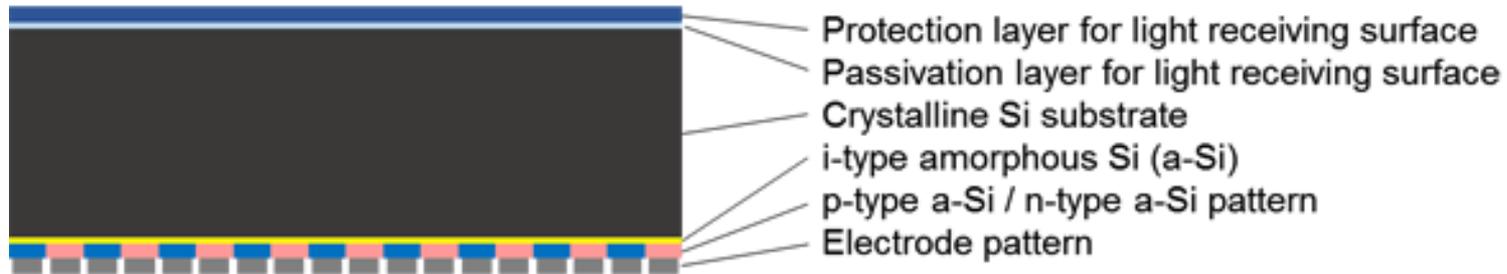
- Physical Limitations
  - Intrinsic Auger recombination, parasitic absorption and transport losses

→ **Back Junction Back Contact**



# From Present to Future

## Back Junction Back Contact with Passivating Contacts



- Kaneka (Heterojunction) 26.6 % (180 cm<sup>2</sup>, da)\*
- Sunpower (Passivating contacts) 25.2 % (153 cm<sup>2</sup>, ta)

\* NATURE ENERGY 2, 17032 (2017) | DOI: 10.1038/nenergy.2017.32

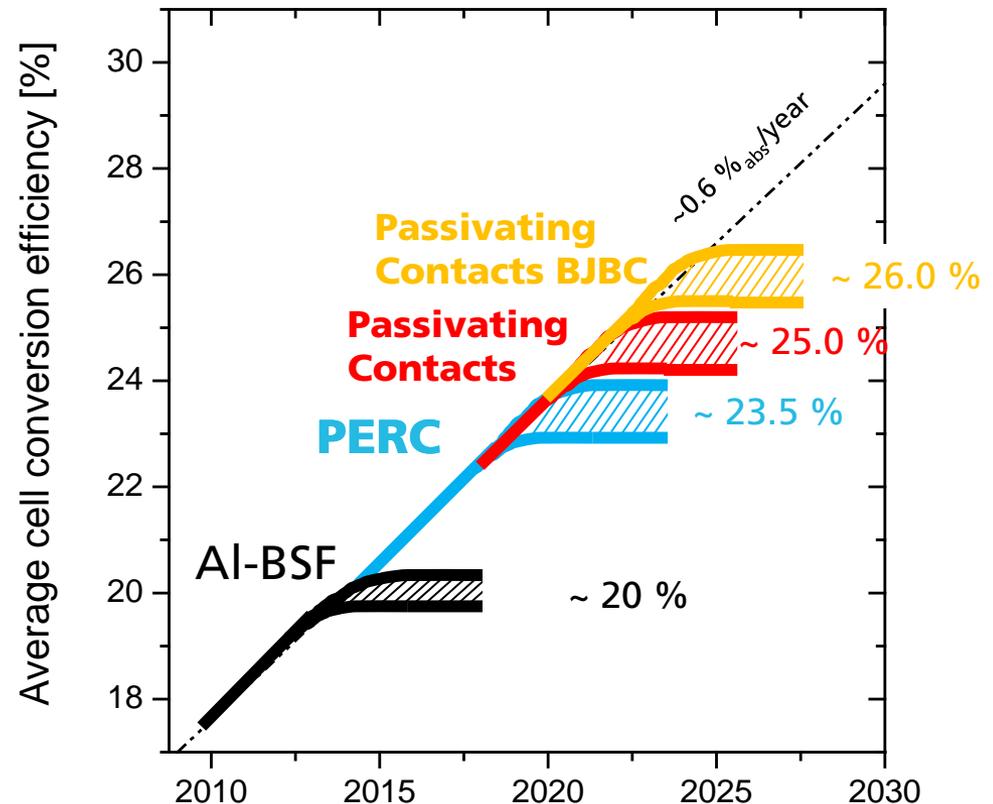
# From Present to Future

## Back Junction Back Contact with Passivating Contacts

### ■ Physical Limitations

- Intrinsic Auger recombination, imperfect light trapping and transport losses

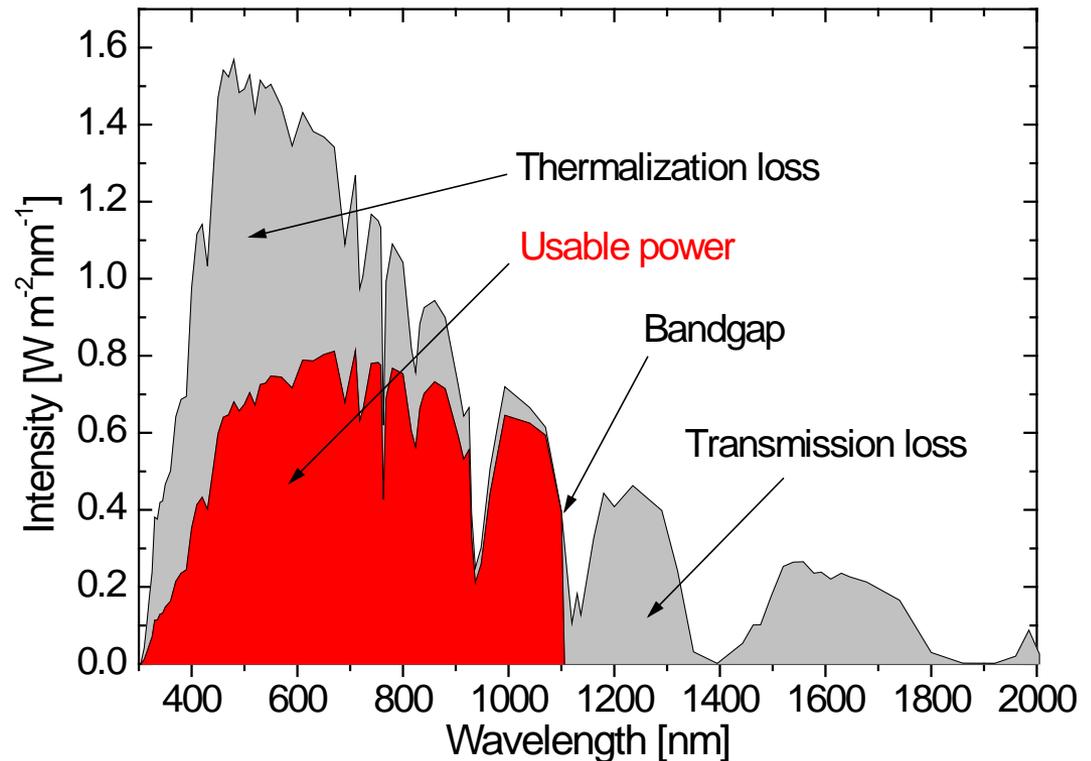
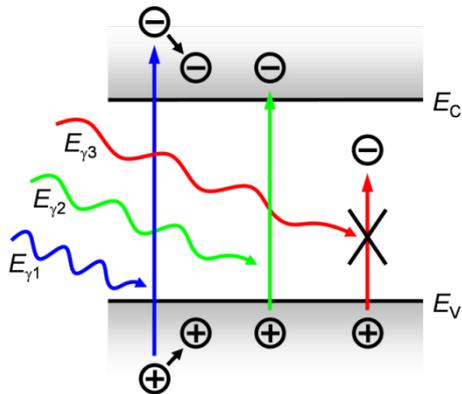
→ And now ?



# Future

## What is the Limit of Silicon Solar Cells

- Shockley, Queisser (1961)  
Limit for Si 33% (AM1.5)
- Limitations by thermalization and transmission
- **Auger Limit 29.4 %<sup>1</sup>**

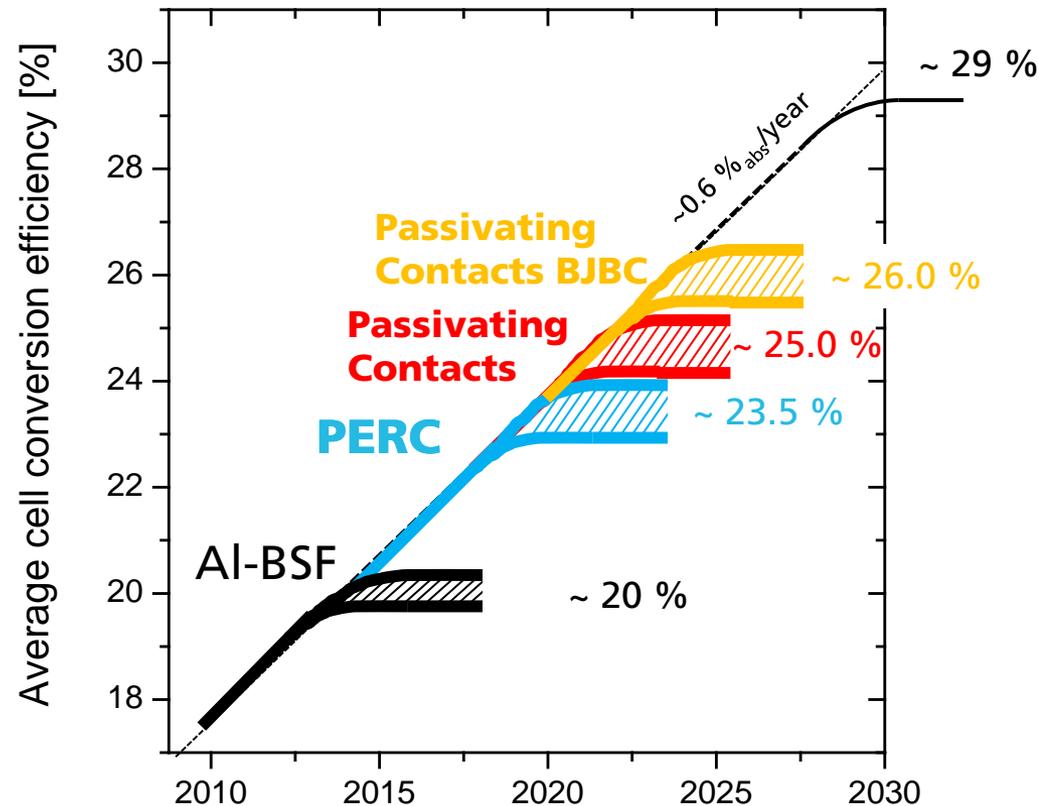
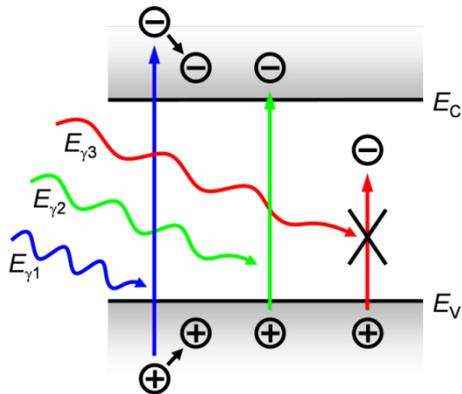


<sup>1</sup>Richter, Hermle, Glunz, *IEEE J. Photovolt.* (2013)

# Future

## What is the Limit of Silicon Solar Cells

- Shockley, Queisser (1961)  
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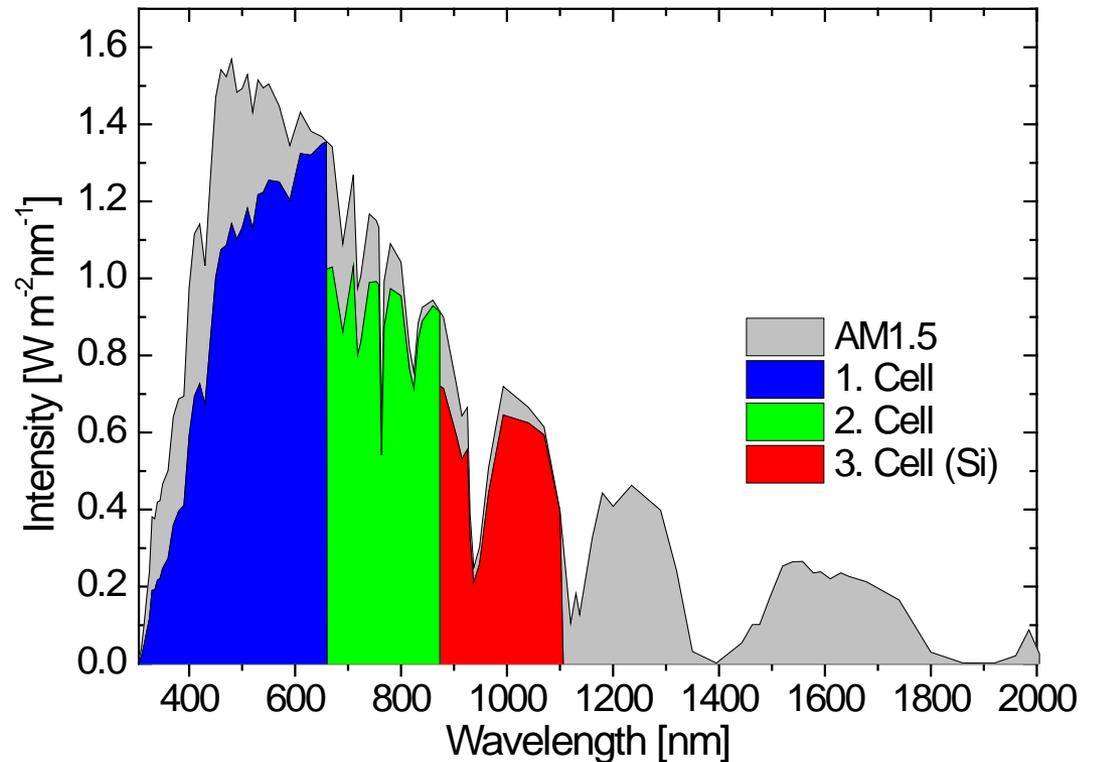
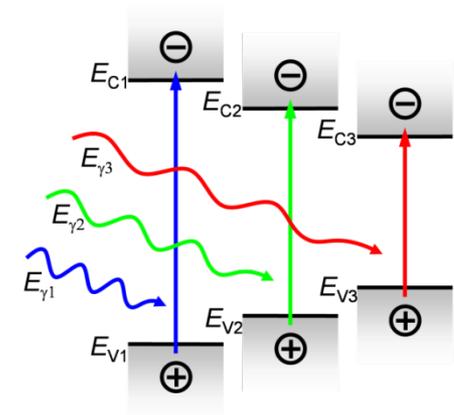
→ End of Silicon Solar Cell Technologies?

<sup>1</sup>Richter, Hermle, Glunz, *IEEE J. Photovolt.* (2013)

# Future

## Beyond the Single Junction-Limit

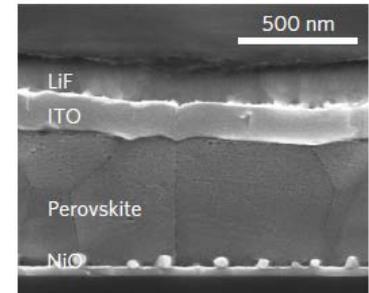
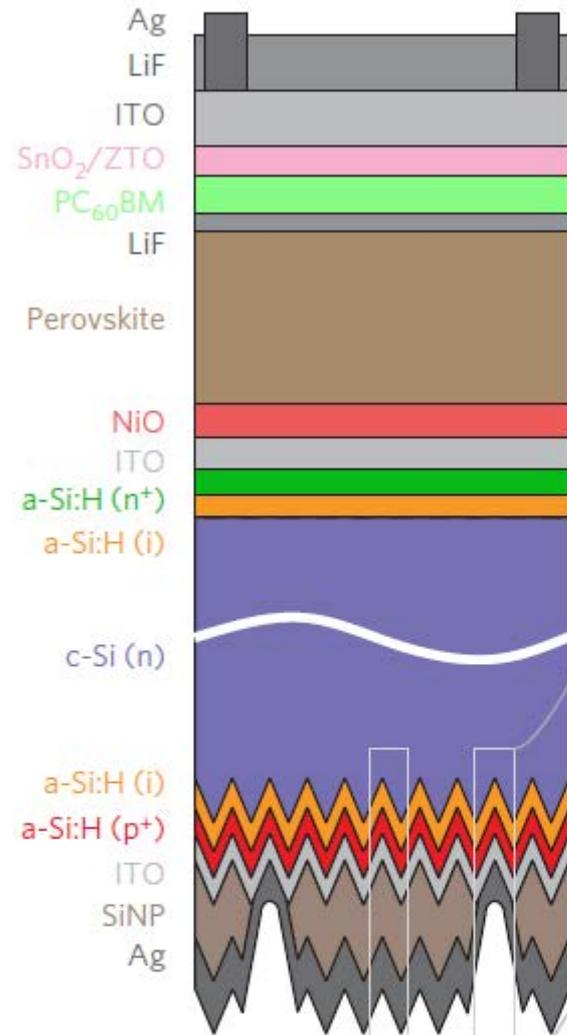
- Light management
  - Up-conversion
  - Down-conversion
- Tandem cells with silicon as bottom cell
  - Perovskite top cell
  - III/V top cell



# Future

## Perovskite / Silicon Tandem

- Perovskite has a wide, tunable bandgap appropriate for a top cell
- Solution processability allows potentially cheap processes
- 23.6 %<sup>1</sup> achieved so far for monolithic 2 terminal devices

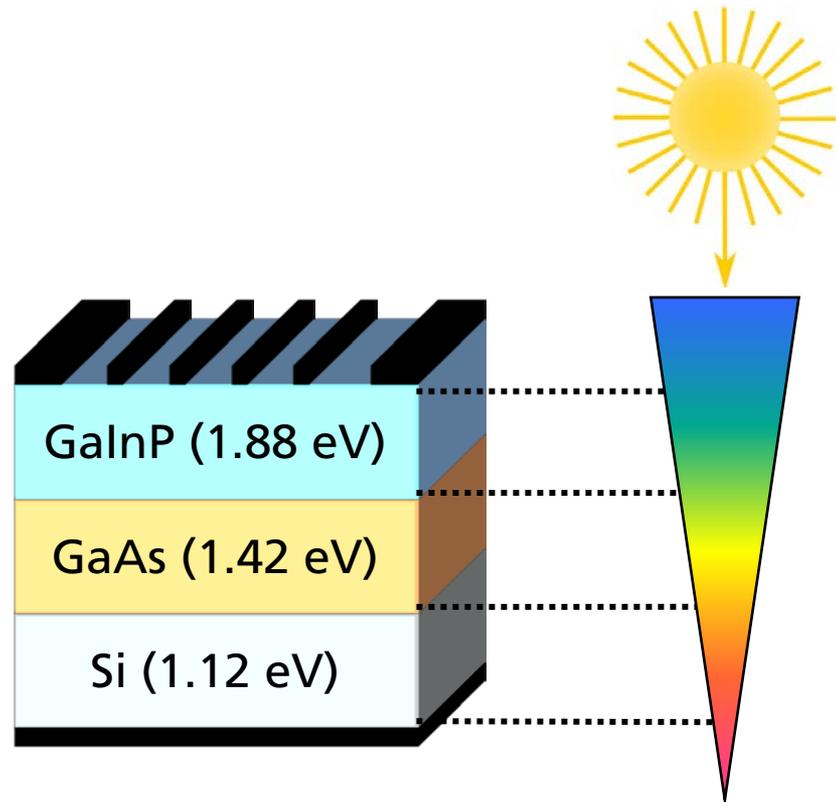


<sup>1</sup>K. Bush et al. *Nature Energy* **2**, Article number: 17009 (2017)doi:10.1038/nenergy.2017.9

# Future

## III/V / Silicon Tandem

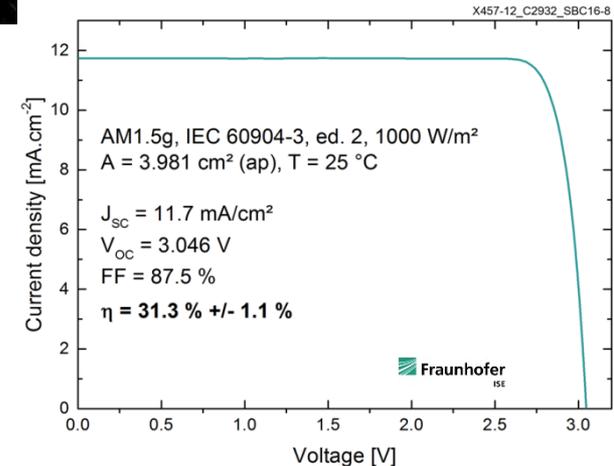
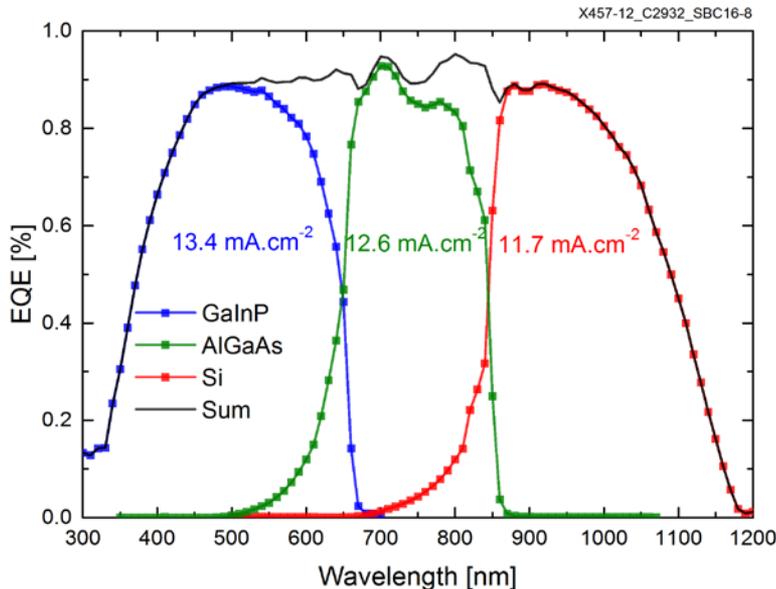
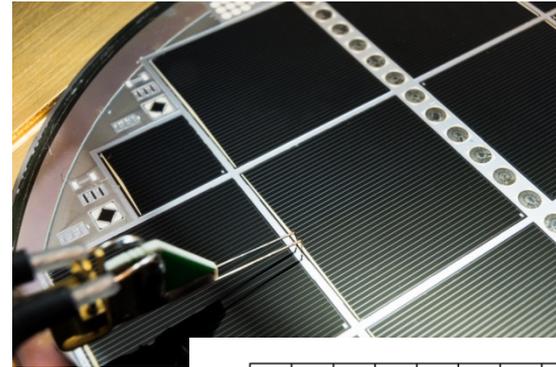
- III/V solar cells have already shown excellent efficiencies
- Deposition by direct epitaxial growth or wafer bonding



# Beyond the Limit

## 2-terminal GaInP/AlGaAs//Si >30% @1-Sun AM1.5g

- Efficient utilization of spectrum
- Efficiency = 31.3%
- Near term potential above 35 %



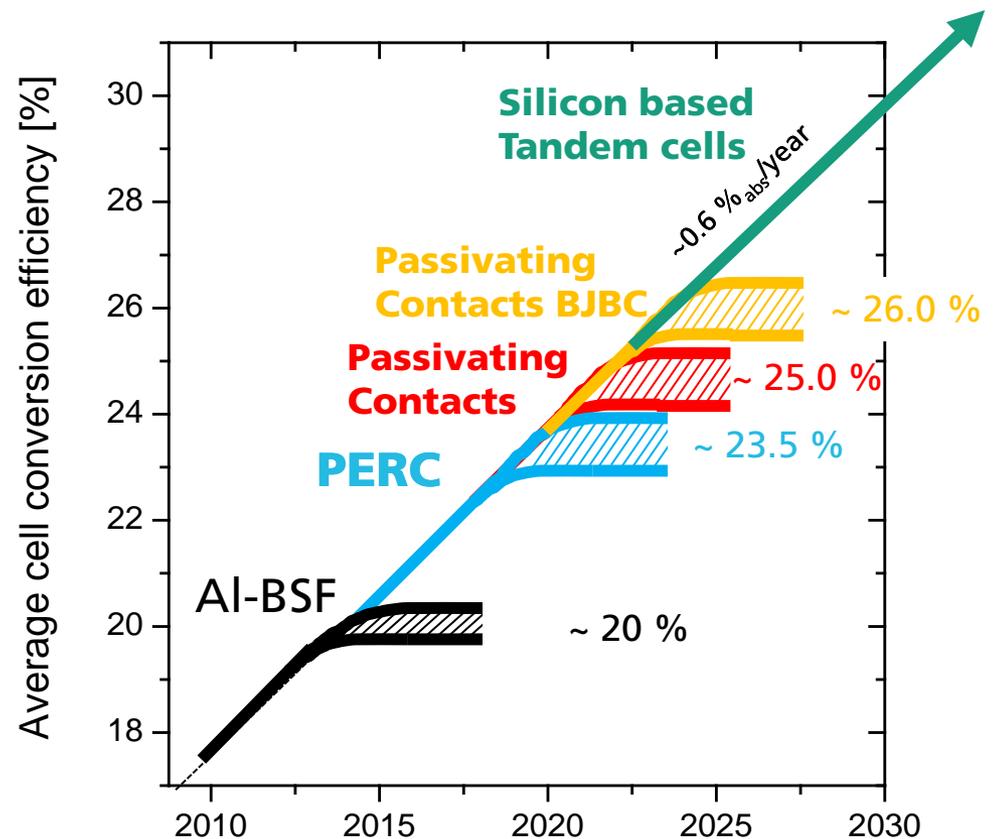
R.Cariou et al **Monolithic III-V//Si Tandem Solar Cells with Efficiency > 30% Enabled by Wafer-Bonding** 7<sup>th</sup> Silicon PV, Freiburg, Germany, April 3, 2017

# Beyond the Limit

## Silicon Based Tandem Cells

→ Silicon Solar Cell Technology has still a bright future

→ R&D is very important to stay on the efficiency "learning curve"



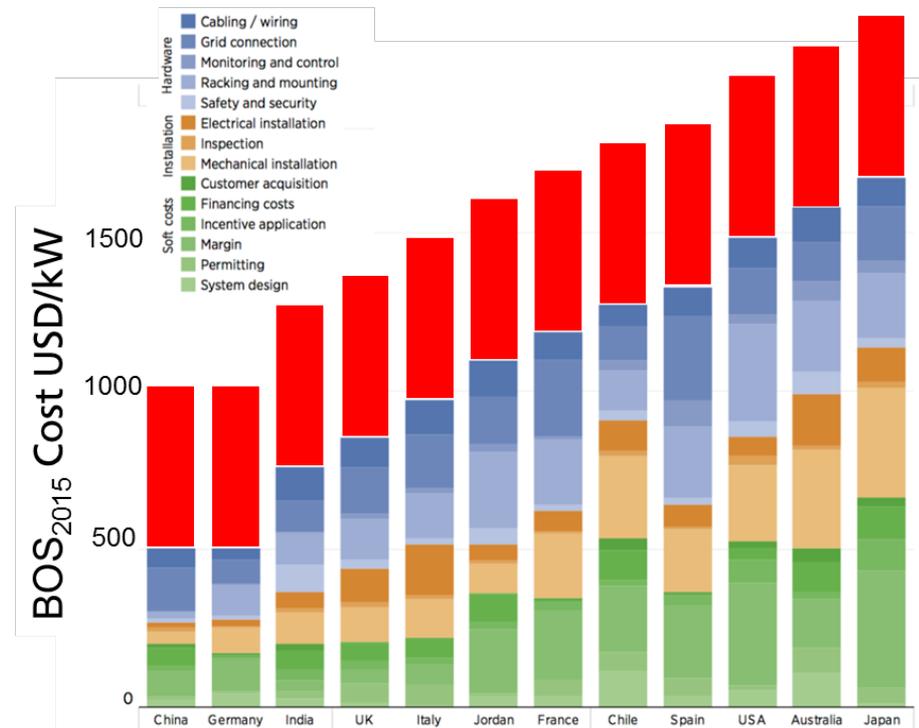
# Conclusion

- Silicon is it the working horse of Photovoltaic



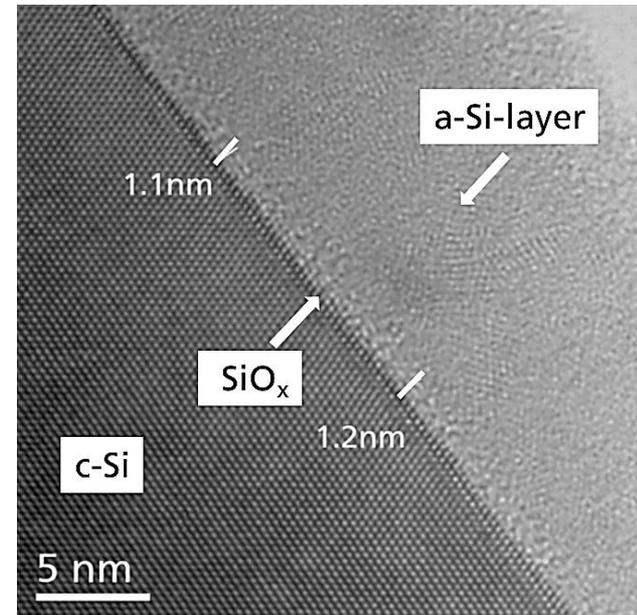
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- Silicon is it the working horse of Photovoltaic
- Conversion efficiency is the key to further bring down the levelized costs of electricity and to survive competition.



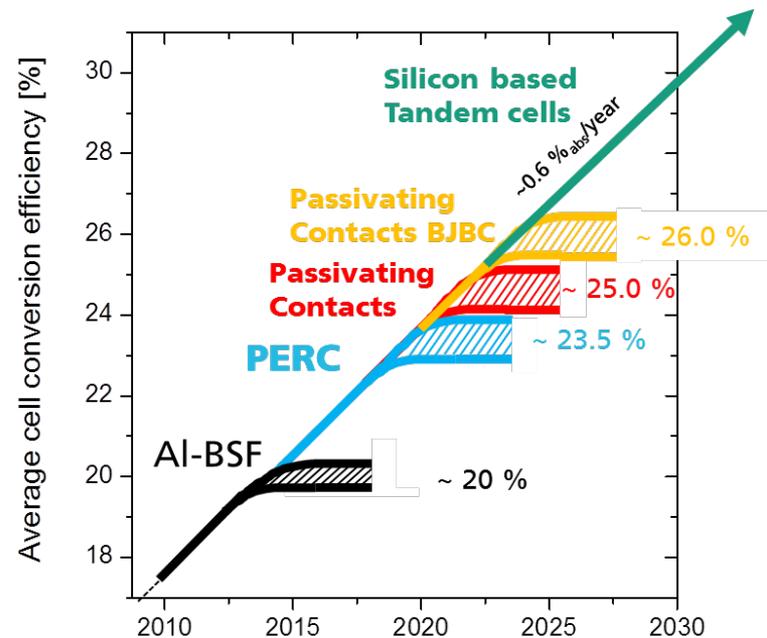
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- Silicon is it the working horse of Photovoltaic
- Conversion efficiency is the key to further bring down the levelized costs of electricity and to survive competition.
- New cell structures with high industrial potential are available

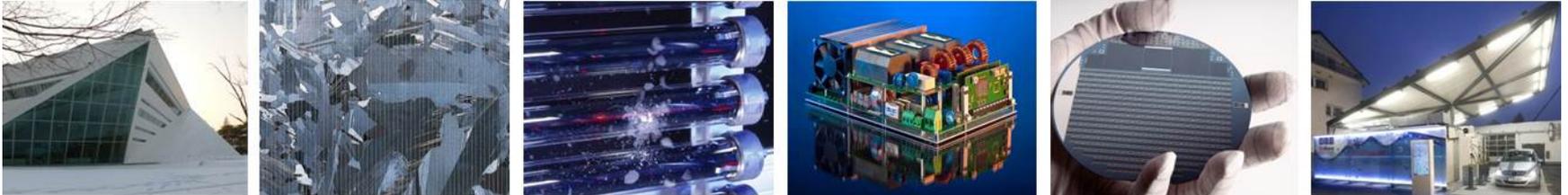


# Conclusion

- Silicon is it the working horse of Photovoltaic
- Conversion efficiency is the key to further bring down the levelized costs of electricity and to survive competition.
- New cell structures with high industrial potential are available
- New fascinating concepts for an old technology:  
Crystalline silicon solar cells **2.0**



# Thank you for your attention!



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